Features

- High Current Gain Bandwidth Product
- These Devices are Pb-Free and are RoHS Compliant

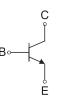


Maximum Ratings (Ta=25°C unless otherwise noted)

| Symbol | Parameter | Value | Unit |
|----------------|--|----------|------|
| Vсво | Collector-Base Voltage | 100 | V |
| Vceo | Collector-Emitter Voltage | 100 | V |
| Vево | Emitter-Base Voltage | 5 | V |
| Ic | Collector Current | 6 | Α |
| PD | Total Device Dissipation | 65 | W |
| ReJC | Thermal Resistance, Junction to Case | 1.92 | °C/W |
| T_j, T_{stg} | Operation Junction and Storage Temperature Range | -65~+150 | °C |

1.BASE 2.COLLECTOR 3.EMITTER

TO-220C



Electrical Characteristics(Ta=25°C unless otherwise specified)

| • | • , | | | | |
|--|-----------------------|----------|-----|------|--|
| Characteristic | Symbol | Min | Max | Unit | |
| Collector–Emitter Sustaining Voltage (Note 1) (I _C = 30 mAdc, I _B = 0) | V _{CEO(sus)} | 100 | | Vdc | |
| Collector Cutoff Current (V _{CE} = 60 Vdc, I _B = 0) | ICEO | | 0.7 | mAdc | |
| Collector Cutoff Current (V _{CE} = 100 Vdc, V _{EB} = 0) | Ices | | 400 | μAdc | |
| Emitter Cutoff Current (V _{BE} = 5.0 Vdc, I _C = 0) | I _{EBO} | | 1.0 | mAdc | |
| DC Current Gain (Note 1) (I _C = 0.3 Adc, V _{CE} = 4.0 Vdc) (I _C = 3.0 Adc, V _{CE} = 4.0 Vdc) | h _{FE} | 30 15 | | | |
| Collector-Emitter Saturation Voltage (Note 1) (I _C = 6.0 Adc, I _B = 1.0 Adc) | V _{CE(sat)} | | 1.5 | Vdc | |
| Base-Emitter On Voltage (Note 1) (I _C = 6.0 Adc, V _{CE} = 4.0 Vdc) | V _{BE(on)} | | 2.0 | Vdc | |
| Current-Gain - Bandwidth Product (Note 2) (I _C = 500 mAdc, V _{CE} = 10 Vdc, f _{test} = 1.0 MHz) | f _T | 3.0 | | MHz | |
| Small-Signal Current Gain (I _C = 0.5 Adc, V _{CE} = 10 Vdc, f = 1.0 kHz) | h _{fe} | 20 | | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

^{1.} Pulse Test: Pulsewidth \leq 300 μ s, Duty Cycle \leq 2.0%.

^{2.} $f_T = h_{fe} \bullet f_{test}$

Typical Characteristics

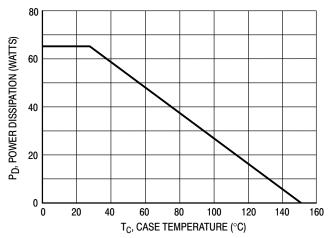
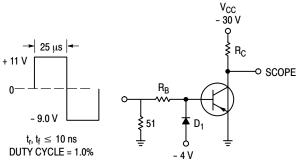


Figure 1. Power Derating



 R_B and R_C varied to obtain desired current levels D_1 must be fast recovery type eg. 1N5825 used above IB \approx 100 ma MSD6100 used below IB \approx 100 ma

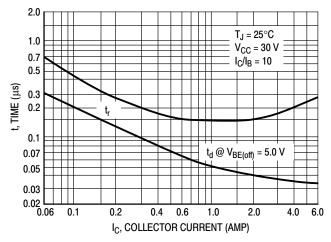


Figure 2. Switching Time Test Circuit Figure 3. Turn-On Time

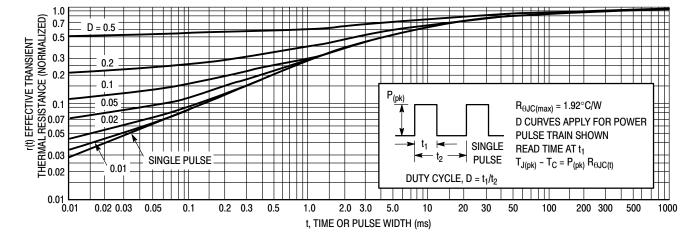


Figure 4. Thermal Response

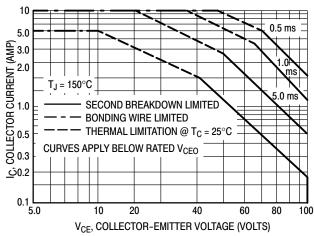


Figure 5. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation, i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on $T_{J(pk)} = 150^{\circ}C$: T_C is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ}C$, $T_{J(pk)}$ may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

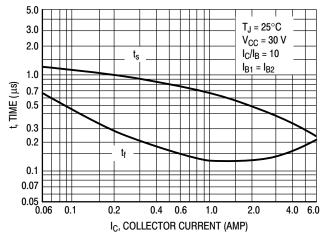


Figure 6. Turn-Off Time

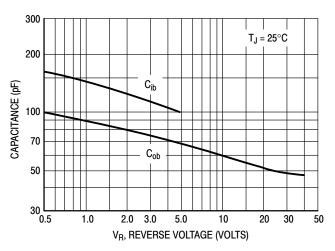


Figure 7. Capacitance

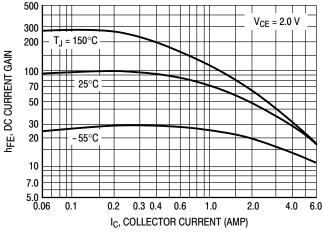


Figure 8. DC Current Gain

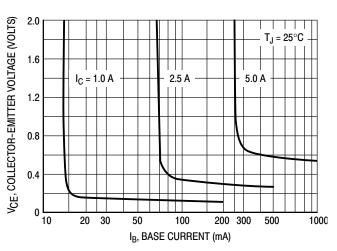
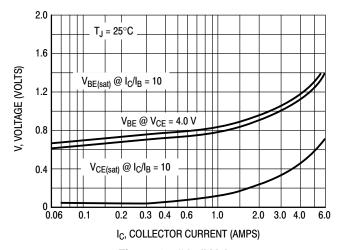
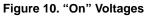


Figure 9. Collector Saturation Region





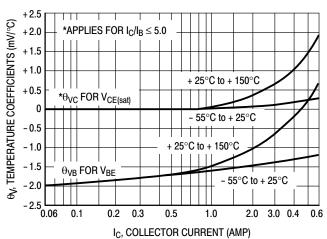


Figure 11. Temperature Coefficients

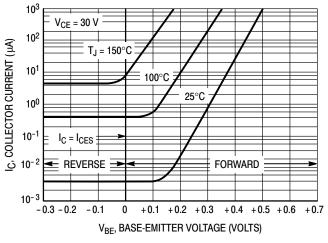


Figure 12. Collector Cut-Off Region

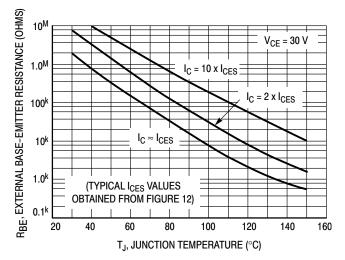
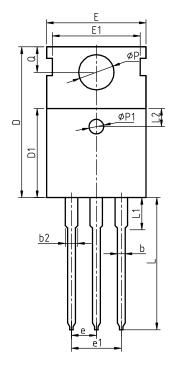
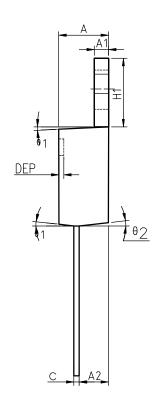


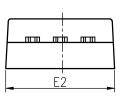
Figure 13. Effects of Base-Emitter Resistance

Package Information TO-220C





COMMON DIMENSIONS



| SYMBOL | MIN | NOM | MAX | MIN | NOM | MAX |
|--------|-------|-------|-------|-------|-------|-------|
| A | 4.40 | 4. 57 | 4.70 | 0.173 | 0.180 | 0.185 |
| A1 | 1. 27 | 1.30 | 1.33 | 0.050 | 0.051 | 0.052 |
| A2 | 2.35 | 2.40 | 2.50 | 0.093 | 0.094 | 0.098 |
| b | 0.77 | 0.80 | 0.90 | 0.030 | 0.031 | 0.035 |
| b2 | 1.17 | 1.27 | 1.36 | 0.046 | 0.050 | 0.054 |
| С | 0.48 | 0.50 | 0.56 | 0.019 | 0.020 | 0.022 |
| D | 15.40 | 15.60 | 15.80 | 0.606 | 0.614 | 0.622 |
| D1 | 9.00 | 9.10 | 9.20 | 0.354 | 0.358 | 0.362 |
| DEP | 0.05 | 0.10 | 0.20 | 0.002 | 0.004 | 0.008 |
| Е | 9.80 | 10.00 | 10.20 | 0.386 | 0.394 | 0.402 |
| E1 | ı | 8.70 | - | - | 0.343 | _ |
| E2 | 9.80 | 10.00 | 10.20 | 0.386 | 0.394 | 0.402 |
| е | | 2.54 | BSC | | 0.100 | BSC |
| e1 | | 5.08 | BSC | | 0.200 | BSC |
| H1 | 6.40 | 6.50 | 6.60 | 0.252 | 0.256 | 0.260 |
| L | 12.75 | 13.50 | 13.65 | 0.502 | 0.531 | 0.537 |
| L1 | - | 3.10 | 3.30 | - | 0.122 | 0.130 |
| L2 | | 2.50 | REF | | 0.098 | REF |
| Р | 3.50 | 3.60 | 3.63 | 0.138 | 0.142 | 0.143 |
| P1 | 3.50 | 3.60 | 3.63 | 0.138 | 0.142 | 0.143 |
| Q | 2.73 | 2.80 | 2.87 | 0.107 | 0.110 | 0.113 |
| θ 1 | 5° | 7° | 9° | 5° | 7° | 9° |
| θ2 | 1° | 3° | 5° | 1° | 3° | 5° |
| θ3 | 1° | 3° | 5° | 1° | 3° | 5° |



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